## NSN 5962-00-232-6795

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-00-232-6795 **Body Length:** Between 0.755 inches and 0.785 inches **Body Width:** Between 0.265 inches and 0.291 inches **Body Height:** Between 0.159 inches and 0.199 inches **Operating Tempurature Range:** +0.0/+75.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** Type angyk3v coordinate data terminal **Features Provided:** Hermetically sealed and monolithic and positive outputs and bipolar and programmable and programmed and w/buffered output and w/decoded output and w/enable and w/open collector **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 10 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -1.5 volts power source and 5.5 volts power source **Time Rating Per Chacteristic:** 60.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Memory Capacity:** Unknown **Test Data Document:** 08241-1742-3013 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a

Yes - demil/mli

**Unit Of Measure:** 

**Demilitarization:** 

## NSN 5962-00-232-6795

Memory Microcircuit - Page 2 of 2



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